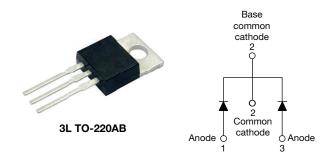
Vishay Semiconductors

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Ultrafast Rectifier, 2 x 10 A FRED Pt[®]



PRIMARY CHARACTERISTICS					
Package	3L TO-220AB				
I _{F(AV)}	2 x 10 A				
V _R	200 V				
V _F at I _F	0.85 V				
t _{rr} typ.	19 ns				
T _J max.	175 °C				
Circuit configuration	Common cathode				

FEATURES

- Ultrafast recovery time
- · Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Designed and gualified according to JEDEC[®]-JESD 47
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

VS-MUR2020CT-M3 is the state of the art ultrafast recovery rectifier specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS	MAX.	UNITS		
Peak repetitive reverse voltage		V _{RRM}		200	V		
Average restified forward surrant	per leg	I _{F(AV)}		10			
Average rectified forward current	total device		Rated V _R , T _C = 145 °C	20			
Non-repetitive peak surge current per leg		I _{FSM}		100	A		
Peak repetitive forward current per leg		I _{FM}	Rated V _R , square wave, 20 kHz, $T_C = 145 \text{ °C}$	20			
Operating junction and storage temperatures		T _J , T _{Stg}		-65 to +175	°C		

ELECTRICAL SPECIFICATIONS (T_J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	200	-	-		
		I _F = 8 A, T _J = 125 °C	-	-	0.85	V	
Forward voltage	V _F	I _F = 16 A	-	-	1.15		
		I _F = 16 A, T _J = 125 °C	-	-	1.05		
Deverse la sluce e summert		$V_{R} = V_{R}$ rated	-	-	15		
Reverse leakage current I _R		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	250	μA	
Junction capacitance	CT	V _R = 200 V	-	55	-	pF	
Series inductance	LS	Measured lead to lead 5 mm from package body	-	8.0	-	nH	

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RoHS COMPLIANT HALOGEN FREE



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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 $^{\circ}$ C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t =$	50 A/µs, V _R = 30 V	-	-	35		
Reverse recovery time	+	$I_F = 0.5 \text{ A}, I_R = 1.0$	I _F = 0.5 A, I _R = 1.0 A, I _{REC} = 0.25 A		-	25	ns	
Reverse recovery time	t _{rr}	T _J = 25 °C	I _F = 10 A dI _F /dt = 200 A/μs V _R = 160 V	-	21	-	115	
		T _J = 125 °C		-	35	-		
Book receiver aurrent	1	T _J = 25 °C		-	1.9	-	٨	
Peak recovery current	I _{RRM}	T _J = 125 °C		-	4.8	-	A	
	0	T _J = 25 °C		-	25	-	20	
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	78	-	nC	

THERMAL MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	e T _J , T _{Stg}		-65	-	175	°C		
Thermal resistance, per	leg		-	-	2.5			
iunction to case	otal R _{thJC} vice		-	-	1.25			
Thermal resistance, junction to ambient per leg	R _{thJA}		-	-	50	°C/W		
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-			
Waiaht			-	2.0	-	g		
Weight			-	0.07	-	oz.		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Marking device		Case style 3L TO-220AB		MUR2	020CT			

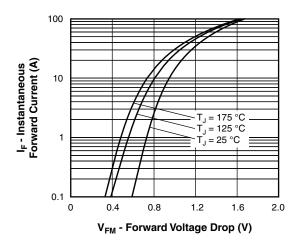
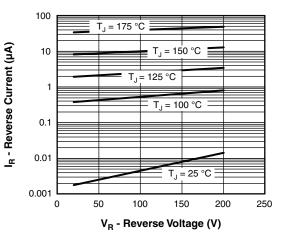
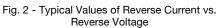


Fig. 1 - Maximum Forward Voltage Drop Characteristics





Document Number: 96201

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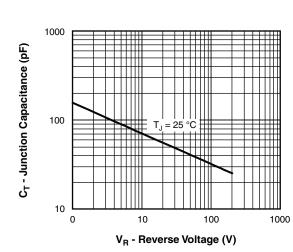


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

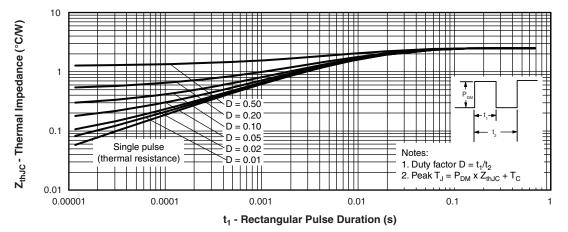
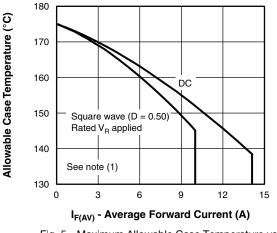
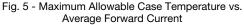
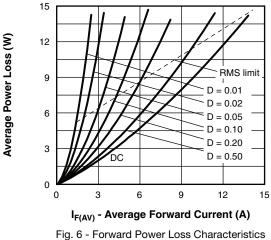


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics



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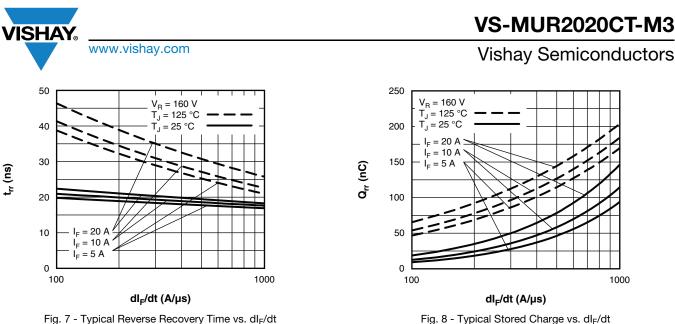


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt



⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

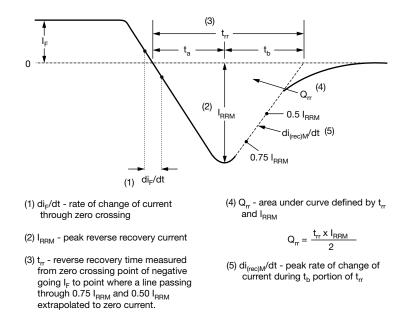


Fig. 9 - Reverse Recovery Waveform and Definitions

1000

VS-MUR2020CT-M3

20 CT M2

Device code	VS-	MUR	20	20	СТ	-M3	
		2	3	4	5	6	
	1 -		,	niconduc		oduct	
	2 -			UR serie	-		
	3 -	- Cur	rent rati	ng (20 =	= 20 A)		
	4 -	- Volt	tage rati	ng (20 =	= 200 V)		
	5 -	- CT	= cente	r tap (du	ial)		
	6 -	- Env	ironmer	ntal digit	:		

20

ve

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-MUR2020CT-M3	50	1000	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?96154			
Part marking information	www.vishay.com/doc?95028			
SPICE model	www.vishay.com/doc?95272			

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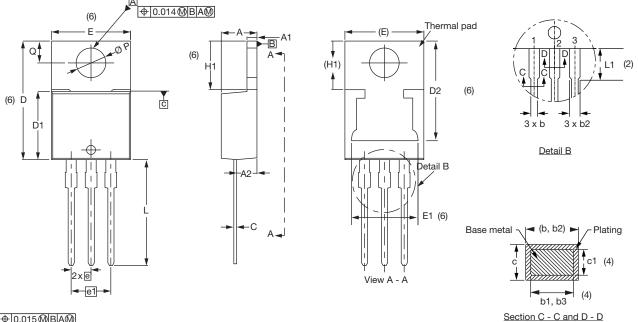




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3L TO-220AB

DIMENSIONS in millimeters and inches



⊕0.015@BA@





SYMBOL	MILLIN	IETERS	INCHES		NOTES	
STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.25	4.65	0.167	0.183		
A1	1.14	1.40	0.045	0.055		
A2	2.50	2.92	0.098	0.115		
b	0.69	1.01	0.027	0.040		
b1	0.38	0.97	0.015	0.038	4	
b2	1.20	1.73	0.047	0.068		
b3	1.14	1.73	0.045	0.068	4	
С	0.36	0.61	0.014	0.024		
c1	0.36	0.56	0.014	0.022	4	
D	14.85	15.35	0.585	0.604	3	
D1	8.38	9.02	0.330	0.355		

_		
Conforms to JEDEC [®]	outline	TO-220AB

SYMBOL	MILLIN	MILLIMETERS		INCHES		
STINDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
D2	11.68	13.30	0.460	0.524	6, 7	
Ш	10.11	10.51	0.398	0.414	3, 6	
E1	6.86	8.89	0.270	0.350	6	
е	2.41	2.67	0.095	0.105		
e1	4.88	5.28	0.192	0.208		
H1	6.09	6.48	0.240	0.255	6	
L	13.52	14.02	0.532	0.552		
L1	3.32	3.82	0.131	0.150	2	
ØР	3.54	3.91	0.139	0.154		
Q	2.60	3.00	0.102	0.118		

Notes

⁽²⁾ Lead dimension and finish uncontrolled in L1

- ⁽⁴⁾ Dimension b1, b3, and c1 apply to base metal only
- (5) Controlling dimensions: inches
- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2, and E1
- ⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

Revision: 13-Jun-2019

 $^{^{(1)}\,}$ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽³⁾ Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body



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